Electronic Supplementary Material for PCCP

Electronic Supplementary Information for

One-pot electrodeposition, characterization and photoactivity of stoichiometric copper indium gallium diselenide (CIGS) thin films for solar cells

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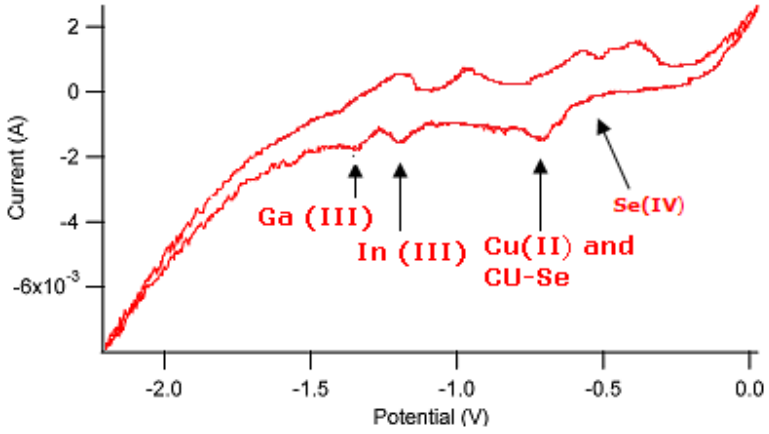

Figure s1 Cyclic voltammogram recorded for Reline containing 7.5 mM $CuCl_2$ + 40 mM $SeCl_4$ + 50 mM $InCl_3$ + 60 mM $GaCl_3$ at 65 °C and scan rate 10 mV s^{-1}.

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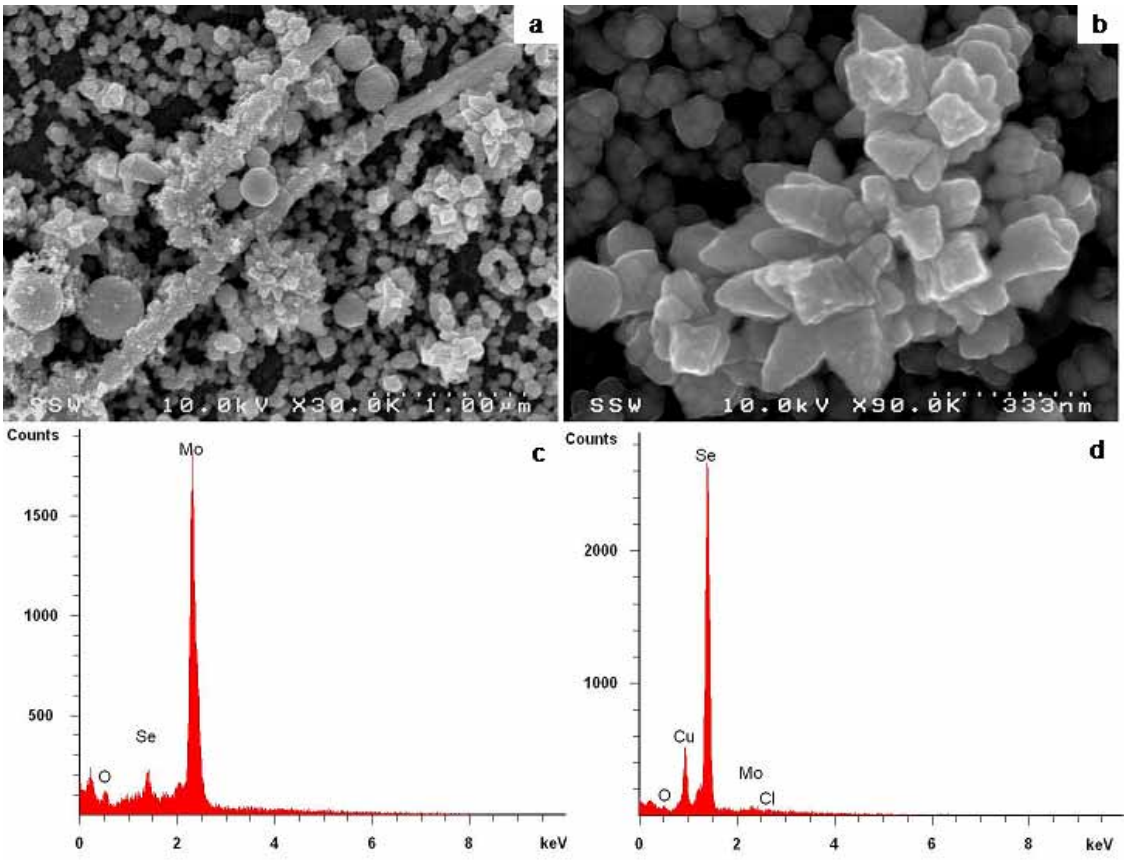

Figure s2 SEM morphology (a-b) and EDX analysis (c-d) of as-deposited CIGS under constant potential for 150 min in 50 mM $GaCl_3$ + 75 mM $SeCl_4$ + 10 mM $CuCl_2$ + 45 mM $InCl_3$ solution at 65 °C.